

# MAGIC LED PLB010050 Series

**Product Datasheet** 

#### **Description**

Plessey MAGIC PLB010050 die are designed for a wide range of low power applications such as decorative lighting, automotive interior, signage and indicators. The light is emitted from the top surface only and close to a Lambertian distribution. The die is suitable for assembling as single devices, or in strings or arrays for specific applications. The dies are supplied on a blue tape in single intensity and colour bin, to provide close uniformity.

#### **Features**

- Blue LED die
- GaN-on-Si technology
- Single surface top-emitting
- Wide wavelength range

### **Applications**

- Decoration Lighting
- Instrument panel backlighting
- Illumination symbols
- Signage
- Displays
- Phosphor driving

		Dominant Wavelength (nm)		
Variant	Colour	Min.	Max.	
PLB010050M	Blue Phosphor	450	460	
PLB010050P	Blue Visible	460	470	
PLB010050T	Blue Visible	470	480	

## **Absolute Maximum Ratings**

 $T_{amb} = +25^{\circ}C$  unless otherwise stated

Parameter	Symbol	Minimum	Maximum	Unit
DC Forward Current	I <sub>F</sub>	-	90	mA
Peak Pulse Forward Current <sup>[1]</sup>	I <sub>FP</sub>	-	120	mA
Reverse Voltage	V <sub>R</sub>	-	5	V
Storage Temperature	T <sub>stg</sub>	-40	+105	°C
Junction Temperature	Ti	-40	+105	°C

<sup>[1]</sup> Pulse width ≤10ms, duty cycle ≤10%

## **Electro-optical Characteristics**

 $T_{amb} = +25$ °C unless otherwise stated

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Forward Voltage	V <sub>F</sub>	$I_F = 60 \text{mA}$	2.8	3.1	3.6	V
Reverse Current	I <sub>R</sub>	$V_R = 5V$	-	-	10	μΑ
			450	_	460	
Dominant wavelength	$\lambda_{d}$	$I_F = 60 \text{mA}$	460	_	470	nm
			470	-	480	
Thermal Resistance	R <sub>thj-m</sub> <sup>[1]</sup>		-	11	-	K/W

<sup>[1]</sup> Junction to mounting face (excluding package)

# **Ordering Information**

Name	Order code	Colour Range	Luminous Intensity Range
PLB010050M	PLB010050MAJ000	M1, M2, M3 & M4	1B, 2B & 3B
PLB010050P	PLB010050PAJ000	P1, P2	2B, 3B & 4B
PLB010050T	PLB010050TAJ000	T1, T2	3B, 4B & 5B

# **Intensity Bin Groups**

 $I_F = 60 \text{mA}$ ,  $T_{amb} = +25 ^{\circ}\text{C}$ , unless otherwise stated

Variant	Group	Luminous Intensity Iv [1] (mcd)		Radiant Power Range (mW) [1]	
		Min.	Max.	Min.	Max.
	1B	-	-	42	47
PLB010050M	2B	-	-	47	52
	3B	-	-	52	57
	2B	440	475	-	-
PLB010050P	3B	475	600		
& BL B040050T	4B	600	750	-	_
PLB010050T	5B	750	1060	_	_

<sup>&</sup>lt;sup>[1]</sup> Tolerance ±11% and packaged with a 1 millimeter radius silicone dome lens (R.I. 1.41)

# **Dominant Wavelength Bin Groups**

 $I_F = 60 \text{mA}$ ,  $T_{amb} = +25 ^{\circ}\text{C}$ , unless otherwise stated

0	λ <sub>d</sub> <sup>[1]</sup>	λ <sub>d</sub> <sup>[1]</sup> (nm)		
Group	Min.	Max.		
M1	450	452.5		
M2	452.5	455		
M3	455	457.5		
M4	457.5	460		
P1	460	465		
P2	465	470		
T1	470	475		
T2	475	480		

<sup>[1]</sup> Tolerance ±1nm

### **Characteristic Curves**

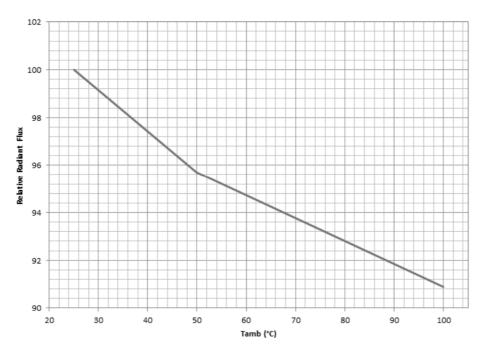


Figure 1: Relative radiant power at  $I_F$ =60mA versus ambient temperature.

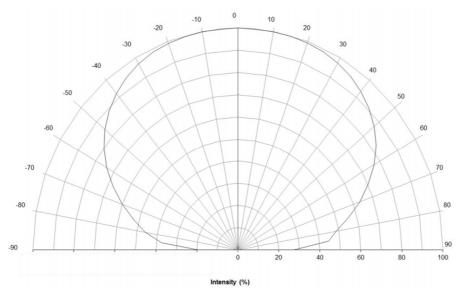


Figure 2: Normalised radiant intensity pattern distribution of a random die sample with a dome lens encapsulation (R.I. 1.4).

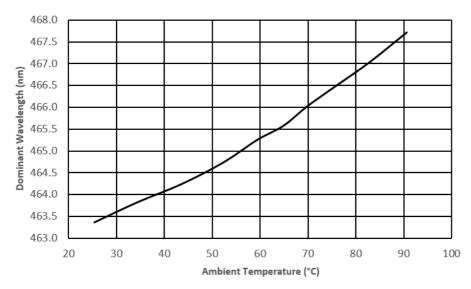


Figure 3: Dominant wavelength versus ambient temperature.

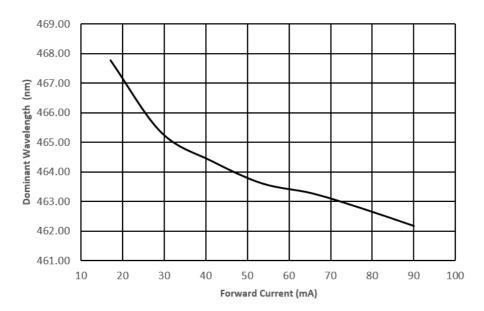


Figure 4: Dominant wavelength versus forward current at +25°C ambient.

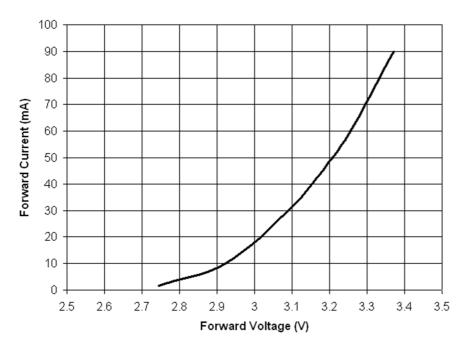


Figure 5. Typical forward voltage versus forward current.

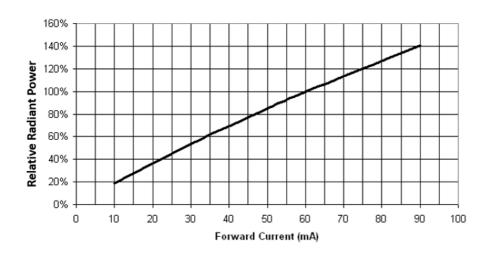


Figure 6. Relative radiant power versus forward current

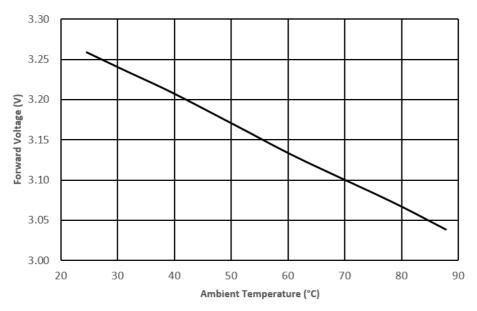
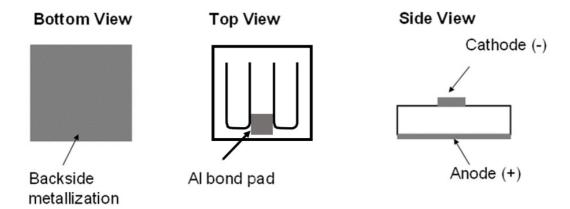


Figure 7. Forward voltage versus ambient temperature

# **Mechanical Specifications**

Description	Dimensions (µm)	Tolerance (µm)
Chip Area	510 x 510	± 10
Chip Thickness	150	± 10
Diameter of top (Al) Bond Pad	100 x 100	± 10
Al Bond Pad Thickness	2	± 0.2
Back Contact Metal (Au) Area	510 x 510	± 10
Back Contact Metal Thickness	1.1	±0.05



## **Handling Instructions**

Plessey LEDs are not designed to operate with reverse bias.

Precautions are required to prevent reverse bias in applications and during handling.



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#### **Contact**

Customer Support +44 1752 693000 | support@plesseysemi.com www.plesseysemi.com

Plessey Semiconductors Ltd | Plymouth Tamerton Road, Roborough Plymouth, Devon PL6 7BQ United Kingdom

P: +44 1752 693000 F: +44 1752 693700 Plessey Semiconductors Ltd | Swindon Design & Technology Centre, Delta 500, Delta Business Park, Swindon SN5 7XE United Kingdom

P: +44 1793 518000 F: +44 1793 518030